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March 2008

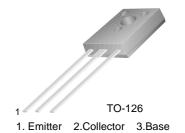
# **2SC3503/KSC3503 NPN Epitaxial Silicon Transistor**

#### **Applications**

- · Audio, Voltage Amplifier and Current Source
- CRT Display, Video Output
- · General Purpose Amplifier

#### **Features**

- High Voltage : V<sub>CEO</sub>= 300V
- Low Reverse Transfer Capacitance :  $C_{re}$ = 1.8pF at  $V_{CB}$  = 30V
- Excellent Gain Linearity for low THD
- High Frequency: 150MHz
- · Full thermal and electrical Spice models are available
- Complement to 2SA1381/KSA1381.



# Absolute Maximum Ratings\* $T_a = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Ratings	Units
BV <sub>CBO</sub>	Collector-Base Voltage	300	V
BV <sub>CEO</sub>	Collector-Emitter Voltage	300	V
BV <sub>EBO</sub>	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current(DC)	100	mA
I <sub>CP</sub>	Collector Current(Pulse)	200	mA
P <sub>C</sub>	Total Device Dissipation, T <sub>C</sub> =25°C T <sub>C</sub> =125°C	7 1.2	W W
T <sub>J</sub> , T <sub>STG</sub>	Junction and Storage Temperature	- 55 ~ +150	°C

<sup>\*</sup> These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

### Thermal Characteristics\* T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Max.	Units
$R_{\theta JC}$	Thermal Resistance, Junction to Case	17.8	°C/W

<sup>\*</sup> Device mounted on minimum pad size

#### **h**<sub>FE</sub> Classification

Classification	С	D	E	F
h <sub>FE</sub>	40 ~ 80	60 ~ 120	100 ~ 200	160 ~ 320

## Electrical Characteristics\* T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_C = 10\mu A, I_E = 0$	300			V
BV <sub>CEO</sub>	Collecto- Emitter Breakdown Voltage	$I_{C} = 1 \text{mA}, I_{B} = 0$	300			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 10 \mu A, I_C = 0$	5			V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> = 200V, I <sub>E</sub> = 0			0.1	μА
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 4V, I_{C} = 0$			0.1	μΑ
h <sub>FE</sub>	DC Current Gain	$V_{CE} = 10V, I_{C} = 10mA$	40		320	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_C = 20$ mA, $I_B = 2$ mA			0.6	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	$I_C = 20$ mA, $I_B = 2$ mA			1	V
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = 30V, I_{C} = 10mA$	A 150			MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = 30V, f = 1MHz	2.6			pF
C <sub>re</sub>	Reverse Transfer Capacitance	$V_{CB} = 30V$ , $f = 1MHz$	1MHz 1.8			pF

<sup>\*</sup> Pulse Test: Pulse Width $\leq$ 300 $\mu$ s, Duty Cycle $\leq$ 2%

# **Ordering Information**

Part Number*	Marking	Package	Packing Method	Remarks
2SC3503CSTU	2SC3503C	TO-126	TUBE	hFE1 C grade
2SC3503DSTU	2SC3503D	TO-126	TUBE	hFE1 D grade
2SC3503ESTU	2SC3503E	TO-126	TUBE	hFE1 E grade
2SC3503FSTU	2SC3503F	TO-126	TUBE	hFE1 F grade
KSC3503CSTU	C3503C	TO-126	TUBE	hFE1 C grade
KSC3503DSTU	C3503D	TO-126	TUBE	hFE1 D grade
KSC3503ESTU	C3503E	TO-126	TUBE	hFE1 E grade
KSC3503FSTU	C3503F	TO-126	TUBE	hFE1 F grade

<sup>\* 1.</sup> Affix "-S-" means the standard TO126 Package (see package dimensions). If the affix is "-STS-" instead of "-S-", that mean the short-lead TO126 package.

2. Suffix "-TU" means the tube packing, The Suffix "TU" could be replaced to other suffix character as packing method.

# **Typical Characteristics**

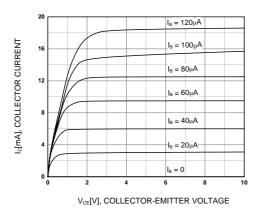


Figure 1. Static Characteristic

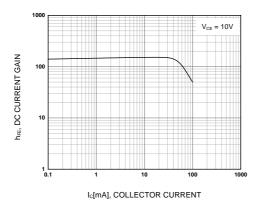


Figure 3. DC current Gain

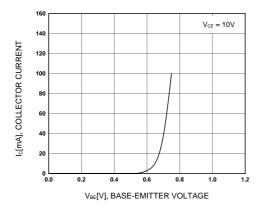


Figure 5. Base-Emitter On Voltage

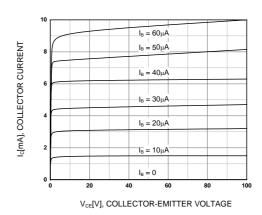


Figure 2. Static Characteristic

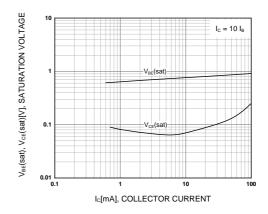


Figure 4. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

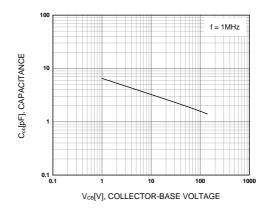


Figure 6. Collector Output Capacitance

# **Typical Characteristics** (Continued)

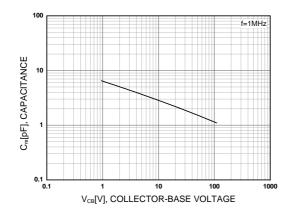


Figure 7. Reverse Transfer Capacitance

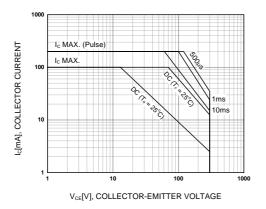


Figure 9. Safe Operating Area

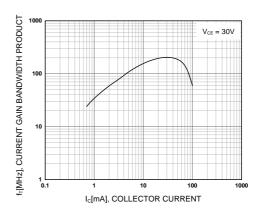


Figure 8. Current Gain Gandwidth Product

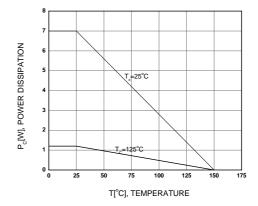
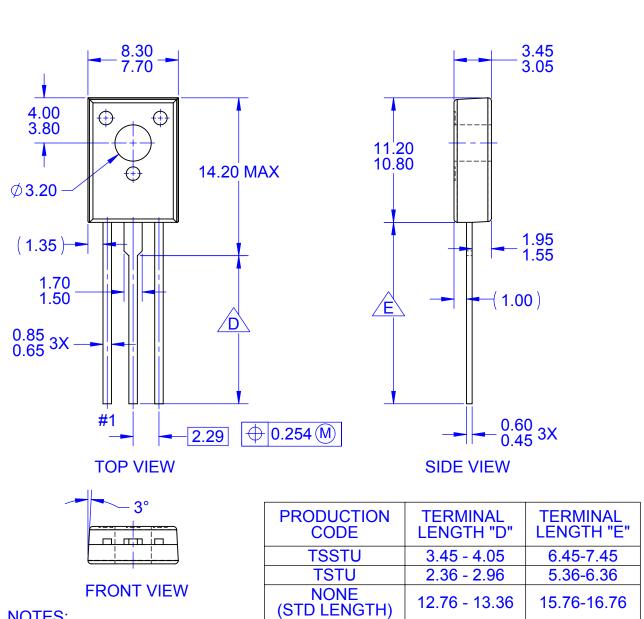


Figure 10. Power Derating



- **NOTES:**
- A. NO INDUSTRY STANDARD APPLIES TO THIS **PACKAGE**
- B. ALL DIMENSIONS ARE IN MILLIMETERS
- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR PROTRUSIONS





FOR TERMINAL LENGTH "E", REFER TO TABLE DRAWING FILENAME: MKT-TO126AArev2

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